

GANOMIC

EPIC Worshop

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CONSORTIUM & PROJECT INTRODUCTION

GaN in One Module Integrated Converter



















CONSORTIUM WORK PACKAGE

WP1- Consortium Management WP2- Requirement ,plans, exploitation and dissemination

WP3-High Frequency Resonant Soft-Switching Isolated 7.5kW Converter









WP4- Digital command & SW integration



WP5-3D Embedding structure & packaging





WP6- 7.5kW Breadboard anode module PPU integration & tests











MAIN OBJECTIVES

- 1. Improvement of power performances (power level and power by weight): Single 7.5 kW building block power module.
- 2. High output voltage management: up to 600V.
- 3. Modularity and configurability: Generic Anode discharge power module with Software digital robust & adaptive control loops.
- 4. Shrink cost: recurrent cost divided by 3 (at PPU level).





Key design drivers of anode module

Efficiency > 98%

(ie < 150W @ 7.5kW)

- New converter topology
- Advanced modulation control for soft-swiching
- New planar transformer architecture

Power density > 2kW/kg*

- GaN transistors (primary & secondary)
- High switching frequency (>500kHz)
- PCB embedded packaging technology

High dielectric voltage > 600V

- PCB embedded packaging technology
- New planar transformer architecture
- New ceramic capacitors dielectric material

Cost divided by 3 at PPU level

- Reduced Bill of material
- Full digital integration of all control loops
- PCB embedded packaging technology

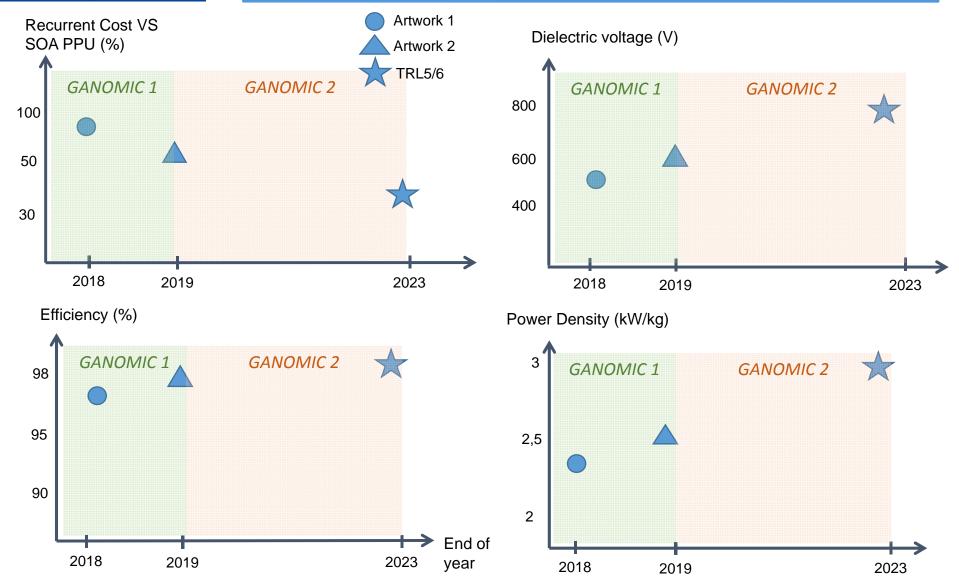
^{*} baseplate, Input & Output Filters included







KDDs progress

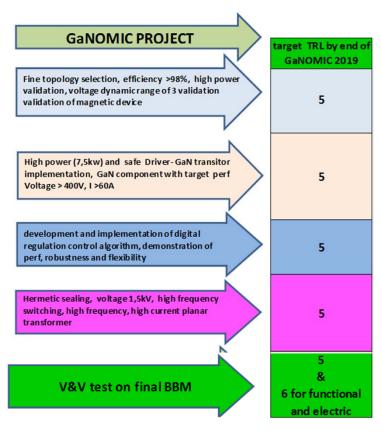






KEY TECHNOLOGY ROADMAP

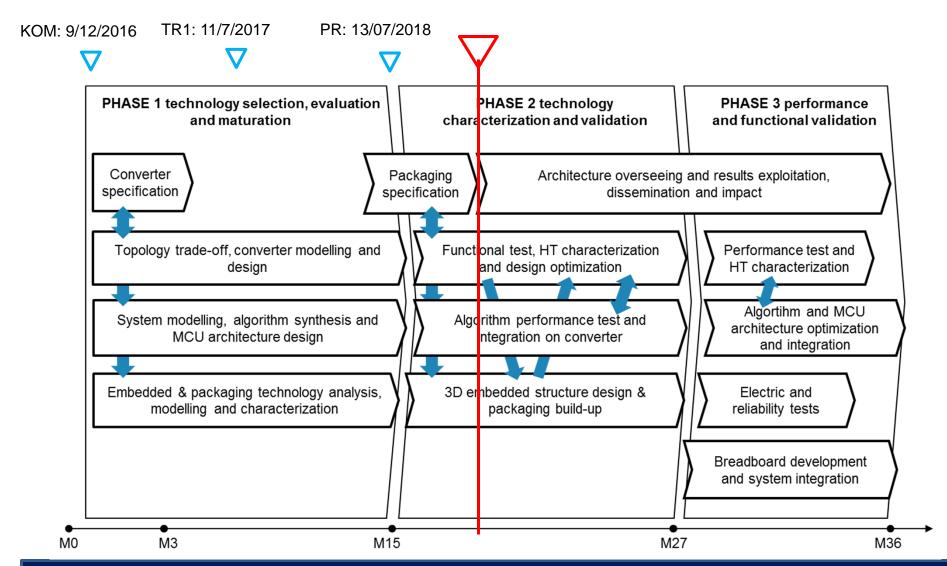
	State of the art starting TRL			
Individual technologies	2016 TRL	Domain	justification	estimated Starting TRL for GaNOMIC / space application
High power resonant topology	4	Aeronautics	Sagem/ UCBL AMPERE Road Map lab Démonstrator running successfully at	3.5 due to higher targeted power and voltage dynamic targeted
High frequency soft-switching power converters			lower power	
GaN switches	4	Aeronautics - Automotive- Industrie research lab	Lab proto up to 3kW	3 .5 due to higher targeted power and no yet proved integrated gate driver and GaN transistor system for safe operation of GaN devices at high switching frequency
Digital control and command integration	3		Sagem on going thesis somes principles already working on breadbord	3.5 Will benefits of Sagem on going thesis work (1 year work at the beginning of GaNOMICS)
3D embedded structure and packaging	4	research lab	already existing breadboard 600V 50kw running at TU Lab	but some additional technologies are TRL 3 (hermetic sealing, high frequency & skin effect, voltage above 600V)
Full embeded 7,5 kw module with the herabove technolgies				







SCHEDULE & PROGRESS

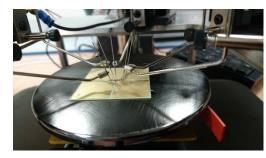




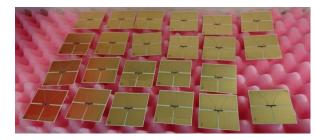


CURRENT RESULTS

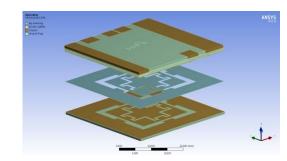
- Electrical characterization of embedded power GaN transistors in PCB and mock-up converters parts.
- 4kW anode module Converter design and electrical & thermal modelling completed.
- Embedded power boards with power circuit & drive in manufacturing.
- Processing ressources evaluation of robust control algorithm software implementation.



Electrical test on B1505 test bench



Test Vehicles of embedding GS66516T



3D embedding power block layout





THANK YOU



